

Contents

Part I Preparation and Characterization of Thin Films for Optoelectronic and Sensoric Applications

1 The Study of Thin Films by Electrochemical Impedance Spectroscopy	3
H. Cesiulis, N. Tsyntsaru, A. Ramanavicius and G. Ragoisha	
1.1 Introduction	4
1.2 Basics of EIS	4
1.3 EIS Responses During Cathodic Metals and Alloys Films Deposition	12
1.4 Anodization of Metals: Characterization of Oxide Films and Their Growth by EIS	17
1.5 The Study of Underpotential Deposition of Metals by EIS	23
1.6 Characterization of Organic Films onto Metals by EIS	26
1.7 Electrochemical Impedance Spectroscopy (EIS) in Development of Biosensors and Biofuel Cells	29
1.8 Conclusions	34
References	34
2 Nanostructures Obtained Using Electric Discharges at Atmospheric Pressure	43
Pavel Topala, Alexandr Ojegov and Veaceslav Ursaki	
2.1 Introduction	43
2.2 Physical Model of Nano-Pellicle Formation by Applying Pulse Electrical Discharge Machining	46
2.3 Processes of Dissociation, Ionization and Synthesis in the Plasma and on the Electrode Surfaces	49
2.4 Diffusion Processes at Oxide Nano-Pellicle Formation by Applyind PEDM	51
2.5 Technology Development	54

2.6	Results of Experimental Investigations and Their Analysis	60
2.6.1	Results of Technological Investigations on Film Formation	60
2.6.2	<i>Phase Composition of Nano-Oxide Films</i>	68
2.6.3	Morphology and Chemical Composition of Nano-Oxide Films	69
2.6.4	Surface Electrical Resistance	71
2.6.5	<i>Resistance to Corrosion</i>	74
2.7	Conclusions.	78
	References	79
3	Graphite Films Deposited on Metal Surface by Pulsed Electrical Discharge Machining	85
	Pavel Topala, Vitalie Besliu and Laurentiu Marin	
3.1	Introduction.	85
3.2	Technology of Graphite Film Forming	86
3.3	Physical Model of Graphite Film Formation by Applying Pulsed Electrical Discharge	88
3.4	Scanning Electron Microscopy Analysis of the Graphite Films	91
3.5	XPS Spectroscopy	96
3.6	Thermal Gravimetric Analysis (TGA) of Graphite Film.	97
3.6.1	TGA Tests on Reference Samples	97
3.6.2	TGA Tests on Experimental Sample by 10/1,5/600/250 Deposition	98
3.7	Solubility of Graphite Films Formed by PED Method on Metal Surfaces	100
3.8	Functional Properties of Graphite Films	102
3.8.1	Anti Socket	102
3.8.2	Antiblocking Properties of Graphite Films.	103
3.8.3	Resistance to Wear for the Graphite Films.	106
3.8.4	Corrosion Resistance of the Graphite Films	108
3.9	Conclusions.	110
	References	111
4	Structural and Physical Properties of $\text{ZnS}_x\text{Se}_{1-x}$ Thin Films.	115
	Mihail Popa	
4.1	Introduction.	115
4.2	Preparation of $\text{ZnS}_x\text{Se}_{1-x}$ Thin Films by Thermal Evaporation Method in Vacuum, in Quasi-Closed Volume	116
4.3	The Structure and Surface Morphology of $\text{ZnS}_x\text{Se}_{1-x}$ Thin Films	117
4.4	The Electrical Properties of $\text{ZnS}_x\text{Se}_{1-x}$ Thin Films	120
4.5	The Optical Properties of $\text{ZnS}_x\text{Se}_{1-x}$ Thin Films.	126

4.6	The Luminescent Properties of $\text{ZnS}_x\text{Se}_{1-x}$ Thin Films	133
4.7	Conclusions	140
	References	141
5	Thin-Film Photovoltaic Devices Based on A^2B^6 Compounds	143
	Tamara Potlog	
5.1	Introduction	143
5.2	Historical Development of the CdS/CdTe Photovoltaic Devices	144
5.3	Technology Development Trends by Companies in CdS/CdTe Photovoltaic Market	146
5.4	Comparison of Moldova State University CdS/CdTe Photovoltaic Device with Manufacturing Target	147
5.5	Deposition Processing and Photovoltaic Device Fabrication . . .	147
5.6	Analysis of Efficiency Loss Mechanism in MSU CdS/CdTe Photovoltaic Devices	150
5.6.1	Current-Voltage Characteristics of the CdS/CdTe Photovoltaic Devices	150
5.6.2	Quantum Efficiency	155
5.7	Characterization of ZnSe/CdTe Photovoltaic Devices	155
5.7.1	Morphological and Structural Studies of Glass/ SnO_2 /ZnSe Interface	155
5.7.2	Optical Properties of ZnSe Thin Films Deposited on SnO_2 /Glass Substrates	161
5.7.3	Current-Voltage Characteristics of the ZnSe/CdTe Photovoltaic Devices	163
5.8	Comparison of CdTe Photovoltaic Devices with Different Buffer Layers	166
5.9	Photovoltaic Devices Based on TiO_2 /CdTe and TiO_2 /CdSe Structures	167
5.9.1	Morphological and Structural Studies of TiO_2 Nanostructured Thin Films	168
5.9.2	XPS Analysis	171
5.9.3	Optical Properties	176
5.9.4	Electrical Properties	179
5.10	TiO_2/p -CdTe and TiO_2/n -CdSe Photovoltaic Devices	180
5.11	Conclusions	182
	References	184

Part II Magnetic Nanomaterials for Spintronic and Sensoric Applications

6 Engineering the Magnetoelectric Response in Piezocrystal-Based Magnetoelectrics: Basic Theory, Choice of Materials, Model Calculations	189
João V. Vidal, Andrey A. Timopheev, Andrei L. Kholkin and Nikolai A. Sobolev	
6.1 Introduction.	190
6.1.1 The Magnetoelectric Effect	190
6.1.2 Magnetoelectric Composites	191
6.2 Theory of the Magnetoelectric Effect	199
6.2.1 Piezoelectricity and Magnetostriction	199
6.2.2 Presentation of the Averaging Quasi-Static Method.	202
6.2.3 Estimation of the Quasi-Static Transversal ME Voltage Coefficients in Magnetostrictive/ Piezocrystalline/Magnetostrictive Tri-Layers.	209
6.3 Conclusions.	218
References	219
7 Dynamic Measurements of Magnetoelectricity in Metglas-Piezocrystal Laminates.	227
João V. Vidal, Andrey A. Timopheev, Andrei L. Kholkin and Nikolai A. Sobolev	
7.1 Introduction.	228
7.2 Magnetoelectric Measurement Techniques	230
7.2.1 Dynamic Magnetoelectric Technique.	230
7.2.2 Experimental Dynamic Magnetoelectric Measurement Setup	234
7.3 Experimental Results	242
7.3.1 Comparative Study of the Direct and Converse Magnetoelectric Effects in Tri-Layered Composites of Metglas with LiNbO_3 and PMN-PT Single Crystals.	242
7.3.2 Comparison of the Anisotropic Magnetoelectric Effects in Tri-Layered Composites of Metglas with LiNbO_3 and GaPO_4 Single Crystals	250
7.4 Conclusions.	260
References	261
8 Peculiarities of Physical Properties of Semimagnetic Semiconductors and Their Practical Application	267
E.I. Gheorghitza, V.I. Ivanov-Omskii and I.T. Postolaki	
8.1 Introduction.	267
8.2 Structure and Parameters of the Energy Bands	268

8.3	Electrical Properties of $\text{Hg}_{1-x}\text{Mn}_x\text{Te}$ and $\text{Hg}_{1-x-y}\text{Cd}_x\text{Mn}_y\text{Te}$ Semimagnetic Semiconductors	273
8.4	Photoelectrical Properties.	278
8.4.1	Photoelectrical Properties of $\text{Hg}_{1-x}\text{Mn}_x\text{Te}$ and $\text{Hg}_{1-x-y}\text{Cd}_x\text{Mn}_y\text{Te}$ in the Absence of Magnetic Field.	279
8.4.2	Photoelectrical Properties in a Magnetic Field	281
8.5	Photoluminescence Properties	284
8.5.1	Photoluminescence Properties in the Absence of Magnetic Field.	284
8.5.2	Photoluminescence Properties in a Magnetic Field	285
8.6	Magneto-Optical Properties	290
8.7	ODMR in Semimagnetic Semiconductors. Optical Orientation	294
8.8	Photoreceivers Based on $\text{Hg}_{1-x}\text{Mn}_x\text{Te}$, $\text{Hg}_{1-x-y}\text{Cd}_x\text{Mn}_y\text{Te}$	295
8.9	Conclusions.	295
	References	296
9	Cobalt/Cobaltoxide Exchange Bias System for Diluted Ferromagnetic Alloy Films in Superconducting Spin-Valves	301
	A.S. Sidorenko, D. Lenk, V.I. Zdravkov, R. Morari, A. Ullrich, C. Müller, H.-A. Krug von Nidda, S. Horn, L.R. Tagirov and R. Tidecks	
9.1	Introduction.	301
9.2	Sample Preparation and Characterization.	303
9.3	Results of Magnetic Measurements and Discussion.	306
9.4	Conclusion	310
	Appendix	310
	References	311
 Part III Nanostructured and Composite Materials		
10	Local Ordering at the Interface of the $\text{TiO}_2\text{-WO}_3$ Bi-Layers	317
	Dan Macovei, Vasile Dăscăleanu, Cristian M. Teodorescu and Dumitru Luca	
10.1	Introduction.	317
10.2	Materials and Methods	319
10.3	Results and Discussion	320
10.3.1	XRD Analysis	320
10.3.2	XPS Analysis	321
10.3.3	Ti K-Edge XANES	323
10.3.4	EXAFS Measurements	324
10.3.5	XPS Analysis of the Interface	328
10.4	Conclusions.	329
	References	330

11 Crystalline Structure and Surface Morphology of A^{III}B^{VI} Type Lamellar Semiconductor Nanocomposites Obtained by Heat Treatment in Cd and Zn Vapor	333
Igor Evtodiev, Iuliana Caraman, Valeriu Kantser, Dumitru Untila, Irina Rotaru, Liliana Dmitroglu, Silvia Evtodiev and Mihail Caraman	
11.1 Introduction	333
11.2 Growth of Single Crystals of A ^{III} B ^{VI} Lamellar Compounds	335
11.3 Crystal Structure of <i>GaS</i> , <i>GaSe</i> , <i>GaTe</i> and <i>InSe</i> Single Crystals	336
11.4 Electrical Properties of the A ^{III} B ^{VI} Compounds (<i>GaS</i> , <i>GaSe</i> , <i>InSe</i> , and <i>GaTe</i>) Undoped and Doped with Group I, II and IV Elements	342
11.4.1 Electrical Properties of A ^{III} B ^{VI} Compounds	342
11.4.2 Structure and Some Physical Properties of <i>Cd</i> and <i>Zn</i> Chalcogenides Thin Films	346
11.5 Crystal Structure and Composition of the Material Obtained by Treatment in <i>Zn</i> Vapors of <i>GaS</i> , <i>GaSe</i> , <i>GaTe</i> and <i>InSe</i> Lamellar Single Crystals	346
11.5.1 Crystal Structure and the Morphology of the Surface and Interface of the Composite Obtained by Heat Treatment of Single Crystal <i>GaS</i> Lamellas in <i>Cd</i> and <i>Zn</i> Vapors	349
11.5.2 The Crystal Structure and the Surface Morphology of Nanolamellar <i>GaSe</i> –Intrinsic Oxide Composites and Composites Prepared by Heat Treatment of ϵ - <i>GaSe</i> Single Crystal Plates in <i>Cd</i> and <i>Zn</i> Vapors	353
11.5.3 Crystal Structure and the Surface Morphology of the Interface Between the Packets of the Composite Obtained by Heat Treatment of <i>GaTe</i> Single–Crystal Lamellas in <i>Cd</i> and <i>Zn</i> Vapors	365
11.5.4 Crystal Structure and the Morphology of the Surface and Interfaces Between the Packets of the Composite Prepared by Heat Treatment of <i>InSe</i> Single–Crystal Lamellas in <i>Cd</i> and <i>Zn</i> Vapors	372
11.6 Conclusions and Generalities	376
References	377
12 Optical and Photoelectric Properties of <i>GaS</i>, <i>GaSe</i>, <i>GaTe</i> and <i>InSe</i> Semiconductors and Nanocomposites Obtained by Heat Treatment in Cd and Zn Vapor	381
Igor Evtodiev, Iuliana Caraman, Valeriu Kantser, Dumitru Untila, Irina Rotaru, Liliana Dmitroglu, Silvia Evtodiev and Mihail Caraman	
12.1 Introduction	382

12.2	Optical and Photoluminescence Properties of Oxide—A ^{III} B ^{VI} Structures	382
12.3	Dispersion of the n_{\perp} and n_{\parallel} Refractive Indices.	384
12.4	Light Absorption in Undoped <i>GaSe</i> , <i>GaS</i> , <i>GaTe</i> and <i>InSe</i> Single Crystals, Doped and Intercalated with <i>Cd</i> and <i>Zn</i>	386
12.4.1	Absorption at the Edge and Depth of Fundamental Band ($h\nu \geq E_g$)	386
12.4.2	Light Absorption of <i>GaSe</i> and <i>GaSe</i> Doped with <i>Cd</i> in the Region of $h\nu < E_g$	404
12.5	Photoelectrical Properties of Nanolamellar Structures with <i>GaS</i> , <i>GaSe</i> , <i>GaTe</i> and <i>InSe</i> Semiconductors	406
12.5.1	<i>Photosensitive Elements on GaTe Semiconductor</i>	406
12.5.2	<i>GaSe–CdSe Heterojunctions</i>	406
12.5.3	<i>InSe–CdSe Heterojunctions</i>	409
12.6	Conclusions and Generalities	410
	References	411
13	Photoluminescence of Nanocomposites Obtained by Heat Treatment of <i>GaS</i>, <i>GaSe</i>, <i>GaTe</i> and <i>InSe</i> Single Crystals in <i>Cd</i> and <i>Zn</i> Vapor	415
	Igor Evtodiev, Iuliana Caraman, Valeriu Kantser, Dumitru Untila, Irina Rotaru, Liliana Dmitroglu, Silvia Evtodiev and Mihail Caraman	
13.1	Introduction.	415
13.2	Photoluminescence of Nanocomposites with <i>GaS</i> Lamellar Semiconductors	416
13.2.1	Undoped <i>GaS</i> and <i>GaS</i> Doped with <i>Mn</i>	416
13.2.2	<i>GaS</i> Intercalated with <i>Zn</i> from Vapor Phase	419
13.2.3	<i>GaS</i> Intercalated with <i>Cd</i> from Vapor Phase	421
13.3	Photoluminescence of Nanocomposites with <i>GaSe</i> Lamellar Semiconductors	421
13.4	Photoluminescence of Nanocomposites with <i>GaTe</i> Lamellar Semiconductors	436
13.5	Photoluminescence of Nanocomposites with <i>InSe</i> Lamellar Semiconductors	439
13.5.1	<i>InSe</i>	439
13.5.2	<i>InSe</i> Intercalated with <i>Cd</i>	440
13.5.3	<i>InSe</i> Intercalated with <i>Zn</i>	441
13.6	Conclusions and Generalities	444
	References	445
14	Nanoreliefs Obtained by Various Machining Methods	447
	Laurențiu Slătineanu, Oana Dodun, Margareta Coteață and Irina Beșliu	
14.1	Introduction.	447
14.2	Possibilities of Characterizing Nanoasperities/Nanoreliefs	449
14.3	Nanoreliefs Obtained by Mechanical Processes	451

14.3.1	General Aspects Concerning the Cutting Process and Its Capacity to Generate Nanoreliefs	451
14.3.2	Nanoreliefs Obtained by Turning	452
14.3.3	Nanoreliefs Obtained by Abrasive Processes	456
14.4	Nanoreliefs Obtained by Electrochemical Processes	461
14.5	Nanoreliefs Obtained by Thermal Machining Processes.	464
14.6	Nanoreliefs Obtained by Hybrid Machining Processes.	466
14.7	Conclusions.	470
	References	470
15	Template Assisted Formation of Metal Nanotubes	473
	Ion Tiginyanu, Veaceslav Ursaki and Eduard Monaico	
15.1	Introduction.	473
15.2	Porous Templates for Nanofabrication.	474
15.3	Production of Metal Nanotubes in Ion-Track Membranes	479
15.4	Metal Nanotubes in Porous Alumina Templates	482
15.5	Semiconductor-Metal Nanocomposites on the Basis of Metal Nanotubes Deposited in Semiconductor Templates	490
15.6	Applications	493
15.7	Conclusions.	501
	References	503
16	Thermal Conductivity of Segmented Nanowires.	507
	Denis L. Nika, Alexandr I. Cocemasov and Alexander A. Balandin	
16.1	Introduction.	507
16.2	Phonons in Segmented Nanowires	509
16.2.1	Face-Centered Cubic Cell Model of Lattice Dynamics in Bulk Crystals	510
16.2.2	Born-von Karman Model of Lattice Dynamics in Bulk Crystals.	512
16.2.3	Lattice Dynamics in Segmented Nanowires	513
16.3	Phonon Engineered Heat Conduction of Segmented Nanowires.	518
16.4	Conclusions.	528
	References	528
17	THz Devices Based on Carbon Nanomaterials	533
	Mircea Dragoman and Daniela Dragoman	
17.1	Introduction.	533
17.2	Graphene Antennas at THz Frequencies	539
17.3	THz Generation Based on Graphene.	543
17.4	THz Detection Based on Graphene and Carbon Nanotubes	545
17.5	Conclusions.	547
	References	548

18 Abrasive Flow Machining	551
N. Ionescu, D. Ghiculesc, A. Visan and V. Avramescu	
18.1 Introduction	551
18.2 Elements of Technological System at Abrasive Flow Machining	552
18.3 Conceptual Design of the AFM Equipment	553
18.4 Detailed Design of the AFM Equipment	555
18.5 Experimental Results	561
18.6 Conclusions	566
References	567
Index	569

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